

Features	 Bandwidth DC 200 MHz Transimpedance (Gain) 2 x 10⁴ V/A Suitable for Source Capacitance up to 8 pF Low Equivalent Input Noise Current of 4.9 pA/√Hz 			
Applications	 Photodiode and Photomultiplier Amplifier Spectroscopy Charge Amplifier Ionisation Detectors Preamplifier for Lock-Ins, A/D Converters, etc. 			
Specifications	Test Conditions	Vs = ± 15 V, Ta = 25°C		
Gain	Transimpedance Gain Accuracy	$2 \times 10^4 \text{ V/A}$ (@ 50 Ω load) $\pm 2 \%$		
Frequency Response	Lower Cut-Off Frequency Upper Cut-Off Frequency (- 3 dB) Max. Source Capacitance Rise / Fall Time (10 % - 90 %) Gain Flatness	DC 200 MHz		
Input	Equ. Input Noise Current Equ. Input Noise Voltage Equ. Integrated Noise Input Bias Current Input Bias Current Drift Offset Current Compensation Input Current Range Input Offset Voltage DC Input Impedance	4.9 pA/ $\sqrt{\text{Hz}}$ (@ 10 MHz) 0.9 nV/ $\sqrt{\text{Hz}}$ (@ 10 MHz) 1.0 μA peak-peak 12 μA typ. 3 nA / °C ± 100 μA adjustable by offset trimpot ± 60 μA (for linear amplification) < 1 mV 56 Ω (virtual) // 5 pF		
Output	Output Voltage Range Max. Output Voltage Range Output Impedance	\pm 1.2 V (@ 50 Ω load) for linear operation and low harmonic distortion \pm 1.7 V (@ 50 Ω load) 50 Ω (terminate with 50 Ω load for best performance)		
Bias Output	Bias Output Voltage Range Bias Output Impedance	\pm 12 V, adjustable by bias trimpot 10 k Ω // 1 μF		

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

F E MT O

Specifications (continued)

High-Speed Current Amplifier

Power Supply	Supply Voltage	± 15 V
	Supply Current	\pm 50 mA typ.
		(depends on operating of

conditions, recommended power supply capability minimum \pm 150 mA)

Weight 210 g (0.5 lbs) Case

Material AlMg4.5Mn, nickel-plated

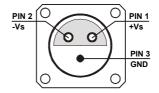
-40 ... +100 °C Temperature Range Storage Temperature 0 ... +60 °C Operating Temperature

Absolute Maximum Ratings $\pm\,5\,V$ Input Voltage Power Supply Voltage \pm 22 V

Connectors **BNC** Input Output **BNC**

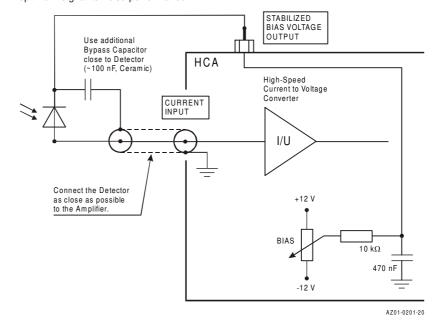
Power Supply LEMO series 1S, 3-pin fixed socket

Pin 1: + 15VPin 2: - 15V Pin 3: **GND**



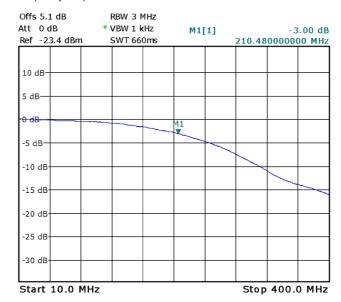
Application Diagrams

Photo Detector Biasing in Photoconductive Mode: Best choice for high speed applications and optimum signal to noise performance.

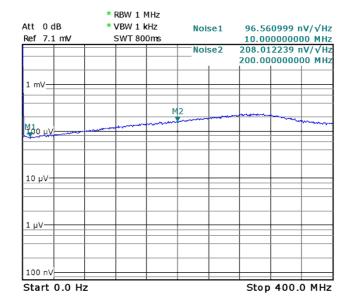


Typical Performance Characteristics

Frequency Response



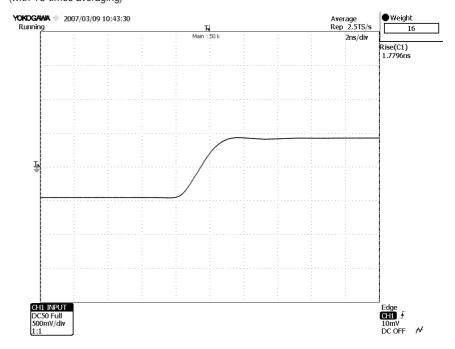
Noise Spectrum



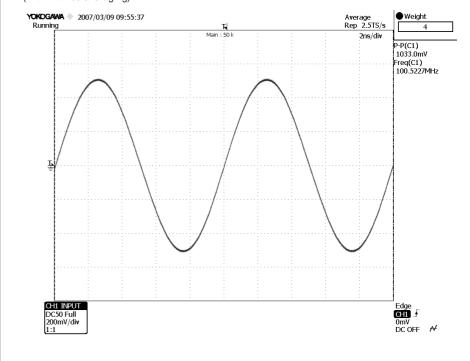
Note: Spectral noise data is measured at the amplifier output with open but shielded input. To determine the spectral input noise divide the measured output noise by the amplifier gain of 2×10^4 V/A, i.e.:

Marker	Frequency	Output Noise	Resulting Input Noise
1	10 MHz	97 nV/√Hz	4.9 pA√Hz 10.4 pA√Hz
2	200 MHz	208 nV/√Hz	10.4 pA√Hz

Typical Performance Characteristics (continued) Pulse Response to Square Wave Input Signal (with 16 times averaging)



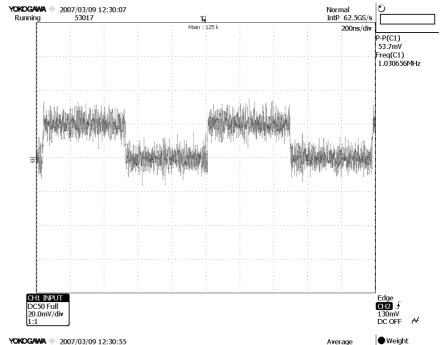
Large Signal Response output signal for 100 MHz, 50 μ A peak-peak input signal (with 4 times averaging)

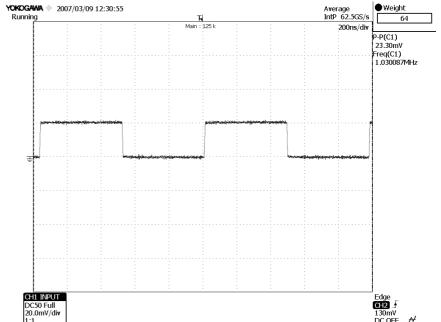


SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

F E M T O

Typical Performance Characteristics (continued) Small Signal Response output signal for 1 MHz, 1 µA peak-peak square wave input signal (without (top) and with 64 times averaging (bottom))

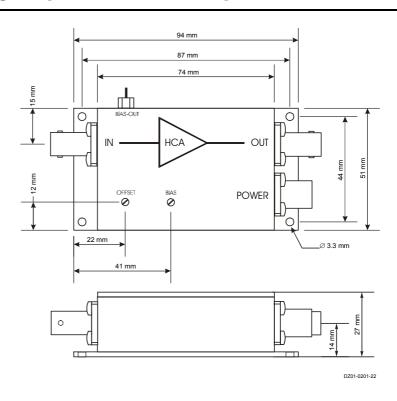




SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

E M T O

Dimensions



FEMTO Messtechnik GmbH Klosterstr. 64 10179 Berlin · Germany Phone: +49 30 280 4711-0 Fax: +49 30 280 4711-11 Email: info@femto.de www.femto.de Specifications are subject to change without notice. Information provided herein is believed to be accurate and reliable. However, no responsibility is assumed by FEMTO Messtechnik GmbH for its use, nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of FEMTO Messtechnik GmbH. Product names mentioned may also be trademarks used here for identification purposes only.

© by FEMTO Messtechnik GmbH · Printed in Germany

F E MT O